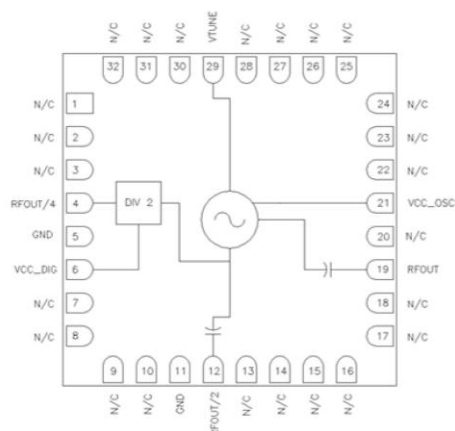


# RFVC1839A

12.44GHz to 13.76GHz MMIC VCO with  
Fo/2 and Fo/4 Outputs

RFMD's RFVC1839A is a 5V InGaP MMIC VCO with an integrated frequency divider providing additional Fo/2 and Fo/4 outputs. With an Fo frequency range of 12.44GHz to 13.76GHz its monolithic structure provides excellent temperature, shock, and vibration performance. Output power (Fo) is +8dBm and is flat across the tuning voltage range of 1.5V to 14.5V. Max Phase noise is -108dBc/Hz at 100kHz offset. The device operates from a low supply current of 270mA which can be further reduced to 210mA by disabling the divider functions if not required. The RFVC1839A is available in a low cost 5mm x 5mm surface mount plastic overmolded QFN outline.



Functional Block Diagram

## Ordering Information

RFVC1839AS2	Sample bag with 2 pieces
RFVC1839ASB	Sample bag with 5 pieces
RFVC1839ASQ	Bag with 25 pieces
RFVC1839ASR	Bag with 100 pieces
RFVC1839ATR7	7" Reel with 750 pieces
RFVC1839APCBA-410	Evaluation Board



Package: Plastic QFN, 32-pin,  
5mm x 5mm x 0.85mm

## Features

- Multiple Frequency Outputs
  - Fo: 12.44GHz to 13.76GHz
  - Fo/2: 6.22GHz to 6.88GHz
  - Fo/4: 3.11GHz to 3.44GHz
- No External Resonator Required
- Integrated Frequency Divider
- Phase Noise: -108dBc/Hz at 100kHz Offset
- Flat Output Power Over Frequency Tuning Range 1.5V to 14.5V
  - Fo: 8dBm
  - Fo/2: 8dBm
  - Fo/4: -2dBm
- Low Power Consumption
  - 5V/270mA (Divider On)
  - 5V/210mA (Divider Off)

32-Lead 5mm x 5mm Plastic  
Overmolded QFN

## Applications

- Point-to-Point Radio
- Point-to-Multipoint Radio
- Satellite Communications
- Test Equipment
- Military
- Aerospace

## Absolute Maximum Ratings

Parameter	Rating	Unit
$V_{CC\_OSC}, V_{CC\_DIG}$	+5.5	V
$V_{TUNE}$	0 to +15	V
Junction Temperature ( $T_J$ )	135	°C
Continuous $P_{DISS}$ ( $T_A = 85^\circ\text{C}$ ) (derate 37mW/°C above $T_A = 85^\circ\text{C}$ )	1.65	W
Junction to Case, Thermal Resistance ( $R_{\theta(j-a)}$ )	30	°C/W
Storage Temperature	-65 to +150	°C
Operating Temperature	-40 to +85	°C
ESD Sensitivity (HBM)	Class 1A	



**Caution!** ESD sensitive device.



RFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, <1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony solder.

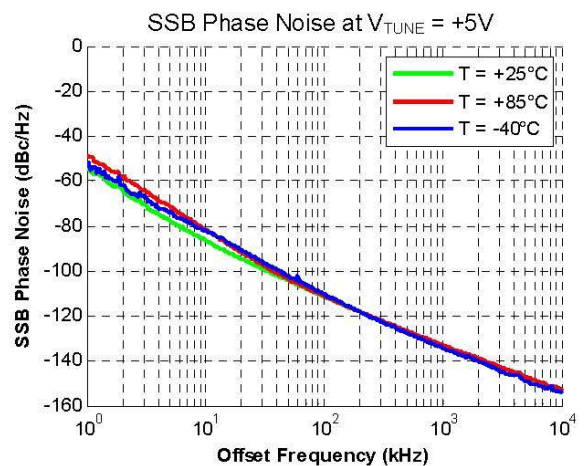
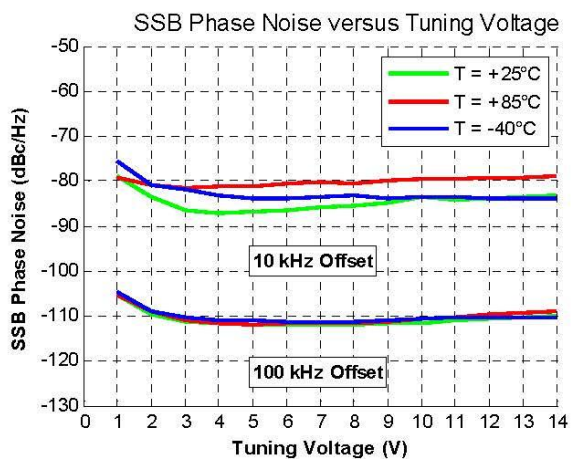
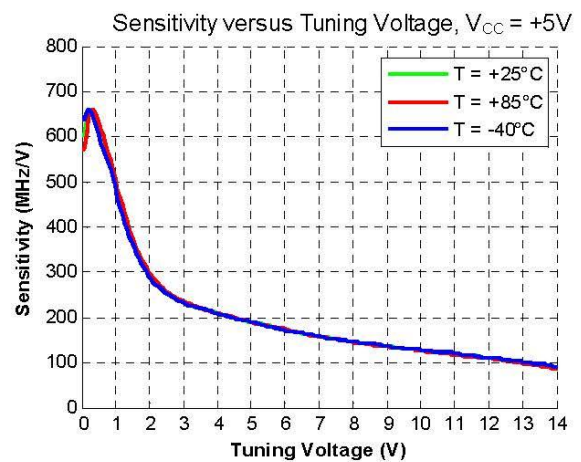
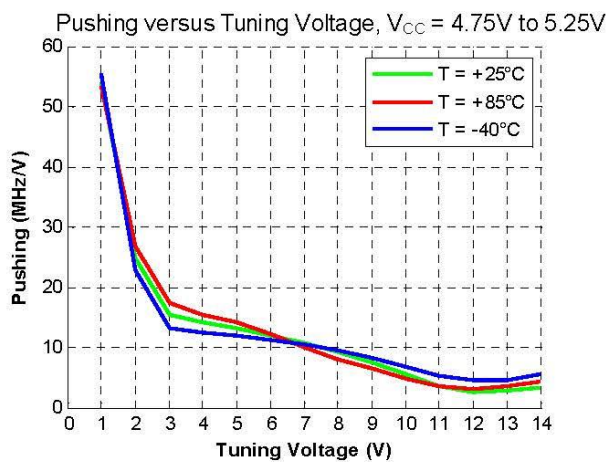
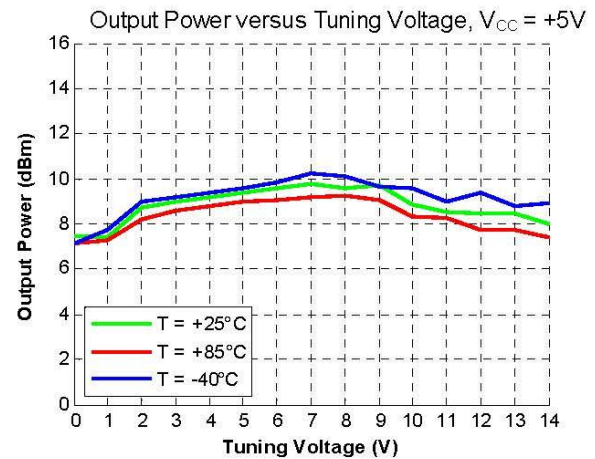
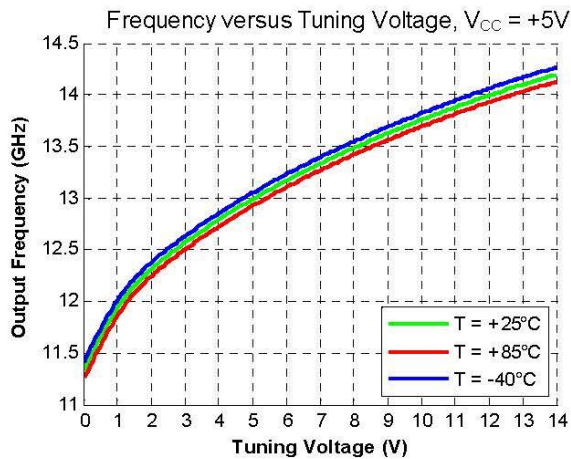
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

## Nominal Operating Parameters

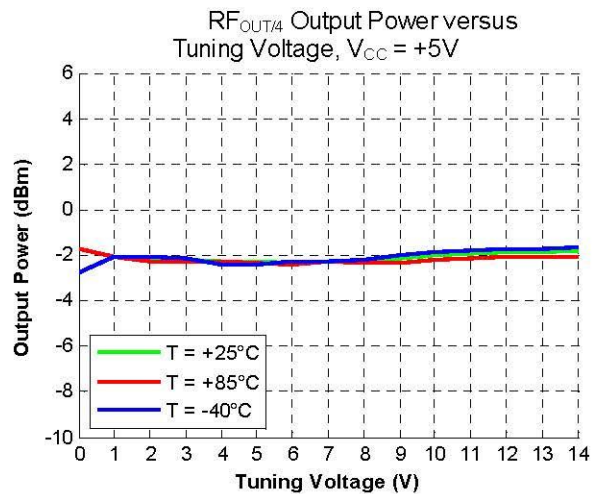
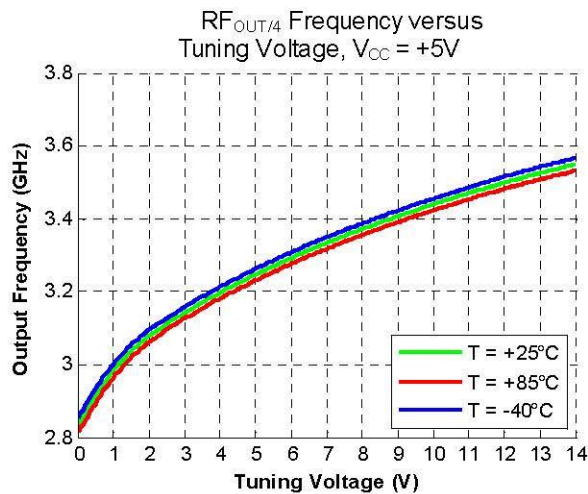
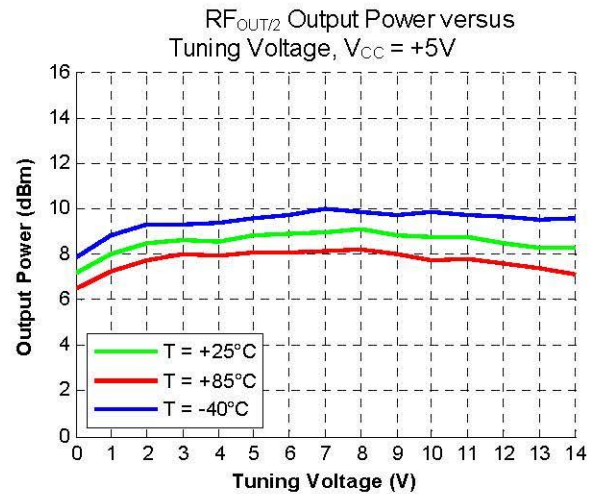
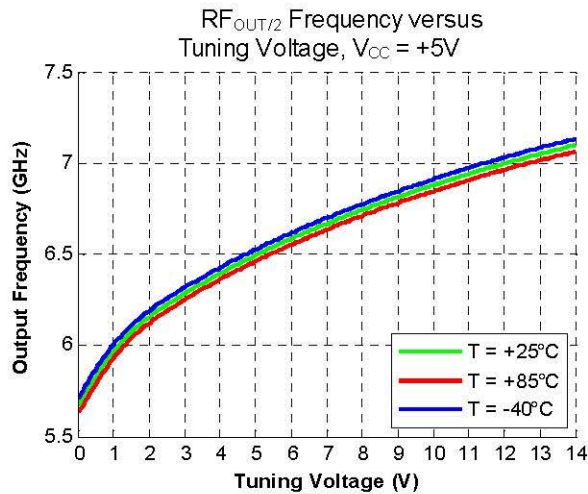
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
Electrical Specifications					V <sub>CC</sub> = 5V, T <sub>A</sub> = +25°C
Operating Frequency					
Fo	12.44		13.76	GHz	
Fo/2	6.22		6.88	GHz	
Fo/4	3.11		3.44	GHz	
Output Power					
Fo		8		dBm	
Fo/2		8		dBm	
Fo/4		-2		dBm	
SSB Phase Noise					
10kHz offset at RF <sub>OUT</sub>		-87	-80	dBc/Hz	V <sub>TUNE</sub> = 5V
100kHz offset at RF <sub>OUT</sub>		-112	-108	dBc/Hz	
Tune Voltage	1.5		14.5	V	
Supply Current					
V <sub>CC_osc</sub>		210		mA	
V <sub>CC_dig</sub>		60		mA	
Tune Port Leakage Current		10		μA	
Output Return Loss		7		dB	

Parameter	Specification			Unit	Condition
	Min	Typ	Max		
<b>Electrical Specifications (continued)</b>					<b><math>V_{CC} = 5V</math>, <math>T_A = +25^{\circ}C</math></b>
Harmonics/Sub-harmonics					Measured with RF probes at package, not at SMA connections on EVB
1/2		40		dBc	
3/2		35		dBc	
2 <sup>nd</sup>		8.5		dBc	
3 <sup>rd</sup>		18		dBc	
Pulling (into a 2.0:1 VSWR)		5		MHz pp	
Pushing		30		MHz/V	
Frequency Drift Rate		1.1		MHz/ $^{\circ}C$	

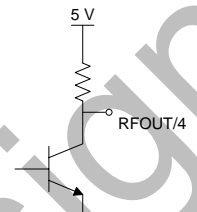

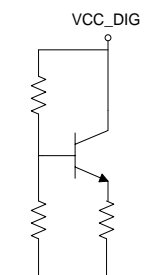
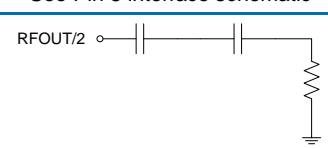
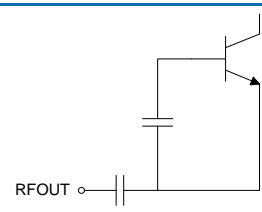
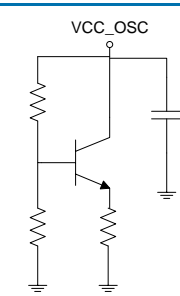
## Typical Performance



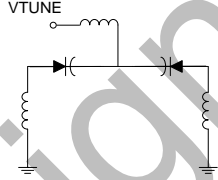
## Typical Performance (continued)



## Pin Names and Descriptions

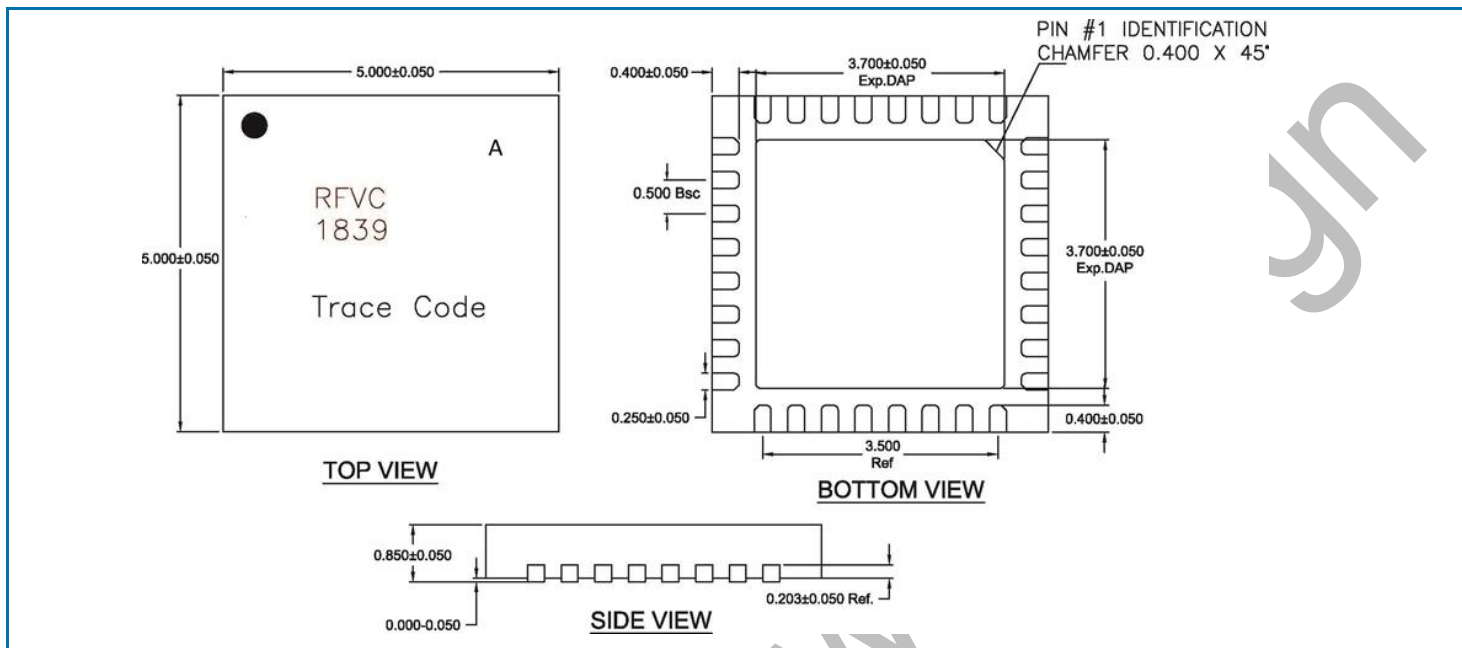
Pin	Name	Description	Interface Schematic
1-3	N/C	No internal connection.	
4	RFOUT/4	VCO RF output at $F_o/4$ . Externally DC-blocked.	
5	GND	Connect to PCB ground.	
6	VCC_DIG	Supply voltage input for the integrated frequency divider. Typical +5 V. Ground this pin to disable digital divider and reduce current consumption by 60mA.	
7-10	N/C	No internal connection.	
11	GND	Connect to PCB ground.	See Pin 5 interface schematic
12	RFOUT/2	VCO RF output at $F_o/2$ . Internally DC-blocked.	
13-18	N/C	No internal connection.	
19	RFOUT	VCO RF output at $F_o$ . Internally DC-blocked.	
20	N/C	No internal connection.	
21	VCC_OSC	Supply voltage input for the VCO. Typical +5V.	

## Pin Names and Descriptions (continued)

Pin	Name	Description	Interface Schematic
22-28	N/C	No internal connection.	
29	VTUNE	VCO control voltage input.	
30-32	N/C	No internal connection.	
PKG BASE	GND	Connect to PCB ground.	See Pin 5 interface schematic



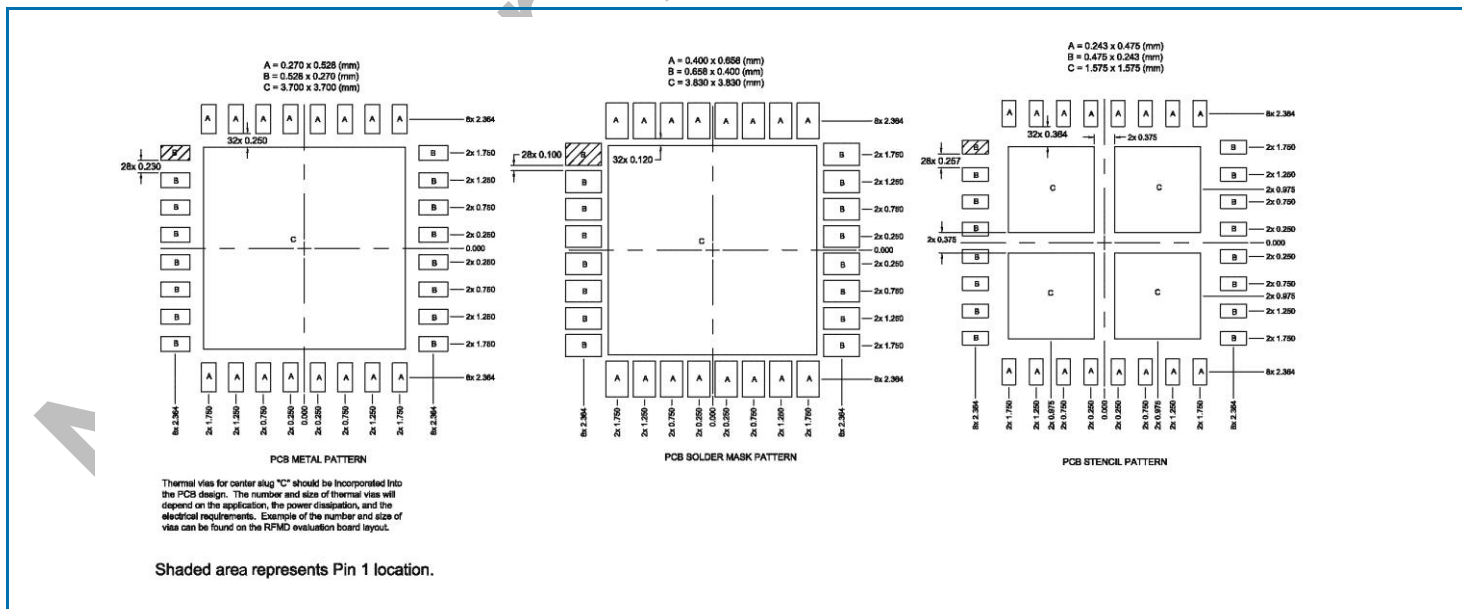
## Package Drawing (all dimensions in mm)



### Notes:

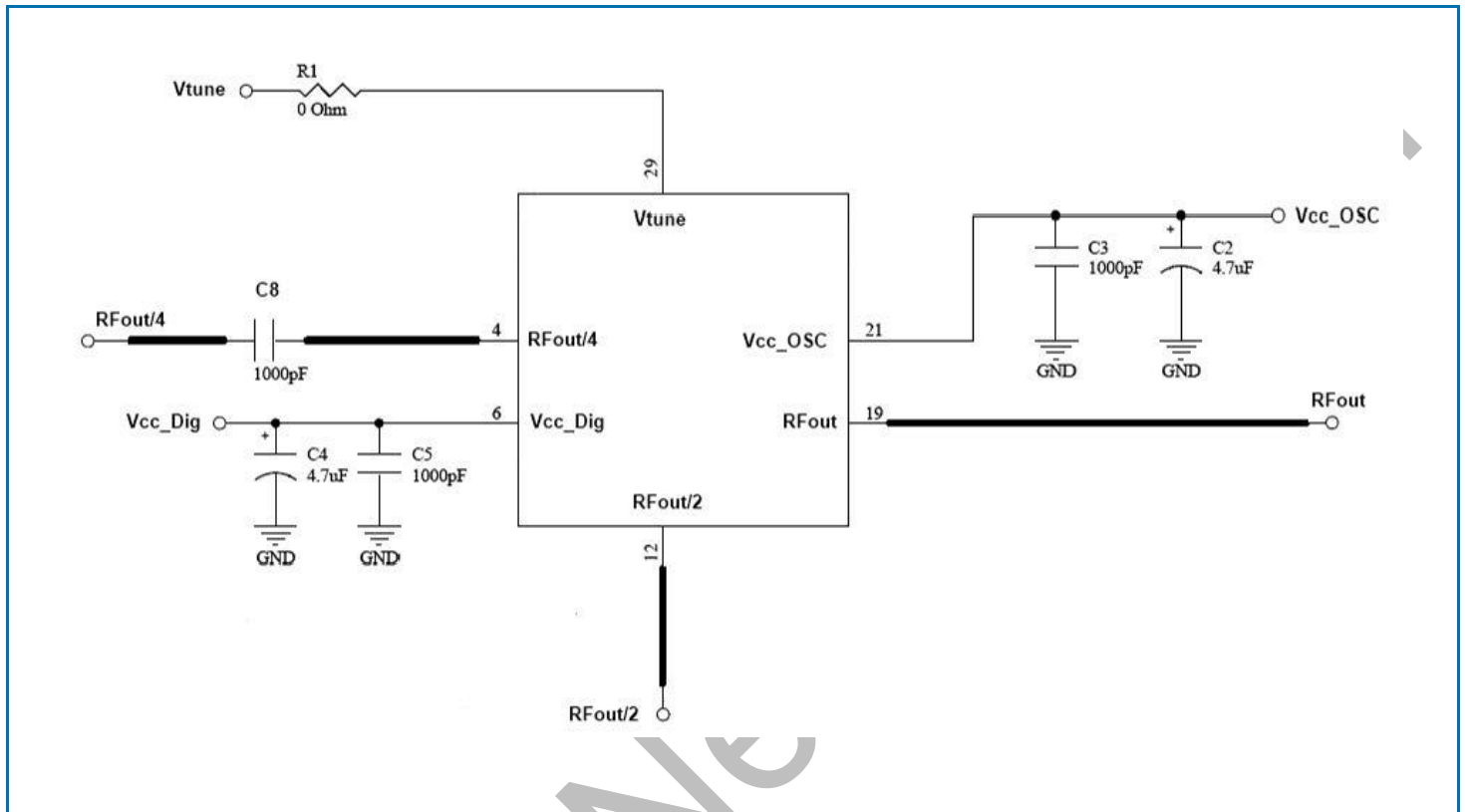
1. Dimensions are for reference only.
2. Package body material: Plastic.
3. Lead and paddle plating: 8µm minimum of Sn over Cu leadframe.

## Recommended PCB Layout



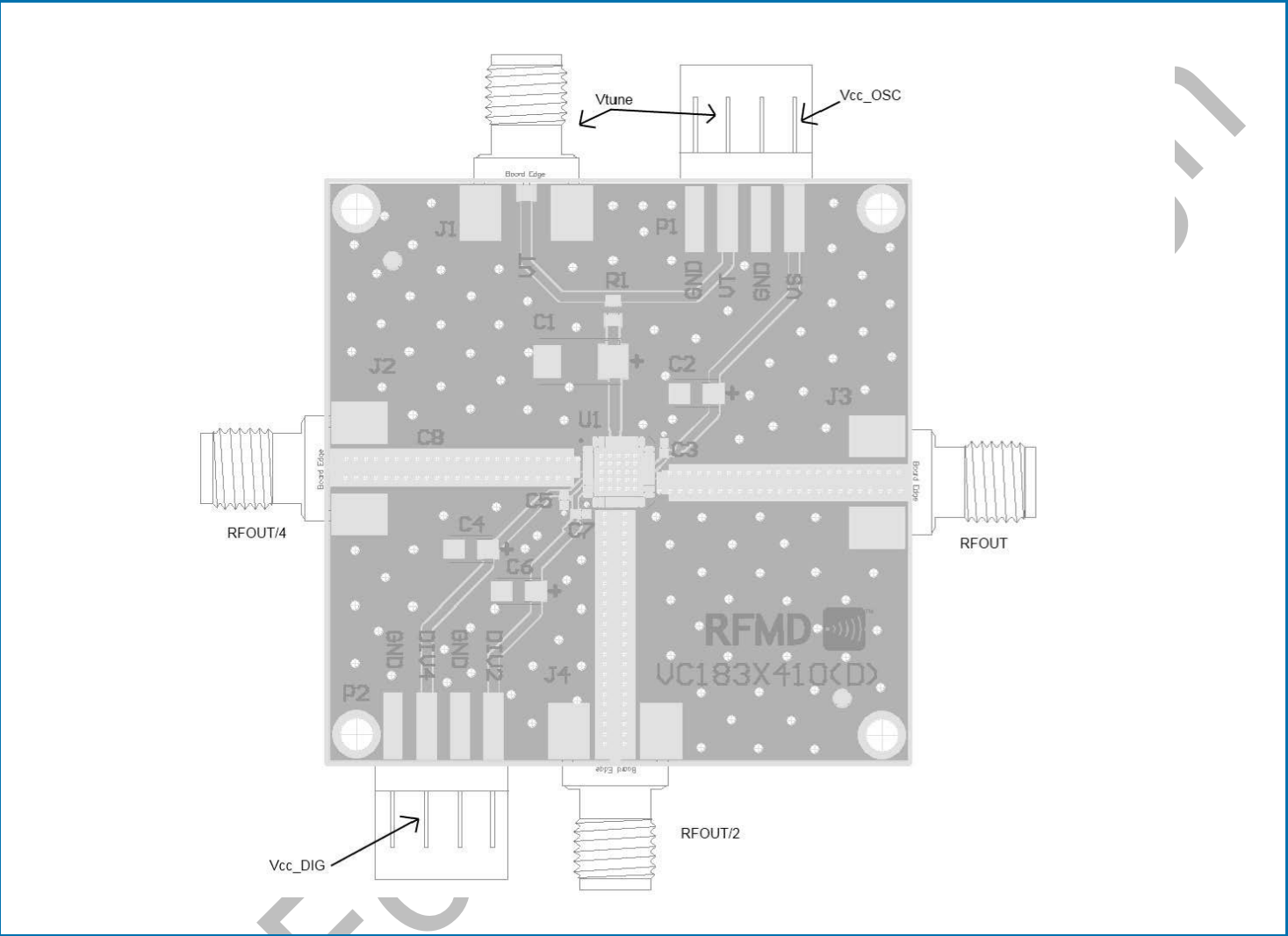


## Sample Application Circuit Schematic



Bias Conditions	Output
$V_{CC\_OSC} = 5V$	$F_{OUT} = 13.0GHz$
$V_{CC\_DIG} = 5V$	$F_{OUT/2} = 6.5GHz$
$V_{TUNE} = 5V$	$F_{OUT/4} = 3.3GHz$

Evaluation Board Layout



Evaluation Board Bill of Materials (BOM)

Item	Description
U1	RFVC1839A VCO
C3, C5, C7, C8	1000pF Capacitor, 0402 Package
C2, C4, C6	4.7μF Tantalum Capacitor
C1	68μF Tantalum Capacitor
R1	0Ω Resistor, 0603 Package
P1, P2	4-PIN DC connector
J1, J2, J3, J4	PCB mount SMA connector
PCB	VC183x410(D)